

# **INFORMATION DISCLOSURE STATEMENT BY APPLICANT** ( Not for submission under 37 CFR 1.99)

Application Number	10677849
Filing Date	2003-10-02
First Named Inventor	Yoshiyuki Abe
Art Unit	1796
Examiner Name	Mark T. Kopec
Attorney Docket Number	KAM 20.660

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/MK/	2	A.E. DELAHOY, et al., "Transparent and semitransparent conducting film deposition by reactive-environment, hollow cathod sputtering" Journal of Vacuum Science and Technology A. Vacuum, Surfaces and Films, June 28, 2005, pg(s) 1215-1220, Vol. 23, no. 4, American Institute of Physics, New York, NY U.S.	<input type="checkbox"/>
/MK/	3	I. SAFI, et al., "The properties of reactively-sputtered, stoichiometry-controlled and optimum-conductivity transparent indium oxide films as a function of their titanium, aluminum and zinc content; comparisons with the use of tin as a dopant", April 1999, vol. 343-344, pg(s) 115-118, Dept. of Physics, Loughborough University, Loughborough, UK.	<input type="checkbox"/>
/MK/	4	G. CAMPET, et al., "The electronic effect of T14+, ZR4+ and GE4+ dopings upon the physical properties of IN203 and SN-doped IN203 ceramics: application to new highly-transparent conductive electrodes", June 20, 1993, pg(s) 285-289, vol. B19, no. 3, Lausanne, CH	<input type="checkbox"/>
/MK/	5	E. HUSENOV, et al., "IR-detectors based on In203-anode oxide-CdxHg1-xTe" International Journal of Infrared and Millimeter Waves, September 2002, vol. 23, no.9, pg(s) 1337-1345, Plenum Publishing Corporation, U.S.	<input type="checkbox"/>
/MK/	6	F.L. SUTHERLAND, et al. "Preparation and properties of transparent conducting films of ZnO and In203", September 1, 1988, pg.(s) 172-175, vol. 3, no. 3, Chemtronics, Butterworth Scientific Ltd., Guildford, GB	<input type="checkbox"/>

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/MK/	8	Summons to attend oral proceedings pursuant to Rule 115(1) EPC dated December 28, 2007 for corresponding European Application EP 03 256 274	<input type="checkbox"/>
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Examiner Signature	/Mark Kopec/	Date Considered	03/07/2008
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